VS-8TQ060-M3, VS-8TQ080-M3, VS-8TQ100-M3

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Vishay Semiconductors

COMPLIANT

HALOGEN

FREE

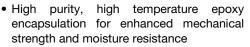
High Performance Schottky Rectifier, 8 A

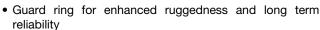


PRIMARY CHARACTERISTICS							
I _{F(AV)}	8 A						
V _R	60 V, 80 V, 100 V						
V _F at I _F	0.58 V						
I _{RM} max.	7 mA at 125 °C						
T _J max.	175 °C						
E _{AS}	7.5 mJ						
Package	TO-220AC 2L						
Circuit configuration	Single						

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- · High frequency operation





- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-8TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES								
I _{F(AV)}	Rectangular waveform	8	Α					
V _{RRM}	Range	60 to 100	V					
I _{FSM}	t _p = 5 μs sine	850	Α					
V _F	8 A _{pk} , T _J = 125 °C	0.58	V					
T _J	Range	-55 to +175	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-8TQ060-M3	VS-8TQ080-M3	VS-8TQ100-M3	UNITS			
Maximum DC reverse voltage	V_{R}	60	80	100	V			
Maximum working peak reverse voltage	V_{RWM}	00	80	100				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS			
Maximum average forward current, see fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 157 °C	8	Α				
Maximum peak one cycle non-repetitive surge current, see fig. 7	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	850	А			
		10 ms sine or 6 ms rect. pulse	V _{RRM} applied	230				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 0.50 A, L = 60 mH		7.50	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.50	Α			



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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
Maximum forward voltage drop See fig. 1		8 A	T _{.1} = 25 °C	0.72	V			
	V _{FM} ⁽¹⁾	16 A	1J=25 C	0.88				
		8 A	T 105 °C	0.58				
		16 A	- T _J = 125 °C	0.69				
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = rated V _B	0.55	mΛ			
See fig. 2		T _J = 125 °C	v _R = rated v _R	7	mA			
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C		pF			
Typical series inductance	L _S	Measured lead to lead 5 m	8	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +175	°C				
Maximum thermal resistance, junction to case		R_{thJC}	DC operation See fig. 4	2.0					
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.50	°C/W				
Approximate weight				2	g				
Approximate weight				0.07	OZ.				
Mounting torque	minimum			6 (5)	kgf ⋅ cm				
Mounting torque —	maximum			12 (10)	(lbf \cdot in)				
Marking device				8TQ060					
			Case style TO-220AC 2L	8TQ080					
				8T(

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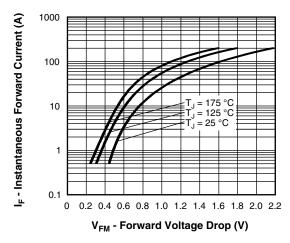


Fig. 1 - Maximum Forward Voltage Drop Characteristics

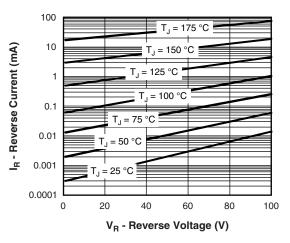


Fig. 2 - Typical Values of Reverse Current vs.Reverse Voltage

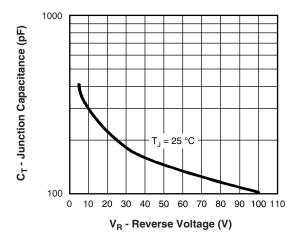


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

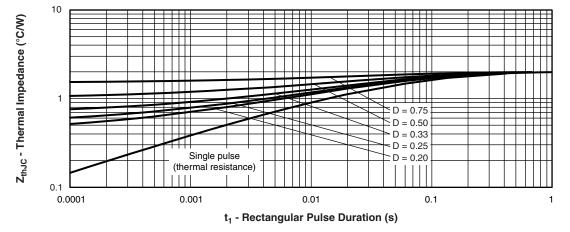


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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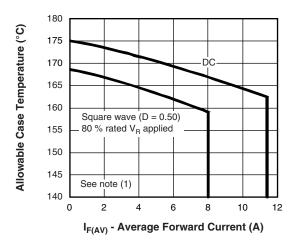


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

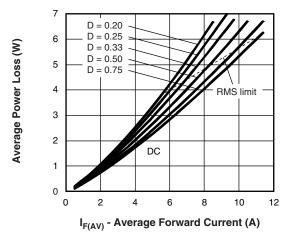


Fig. 6 - Forward Power Loss Characteristics

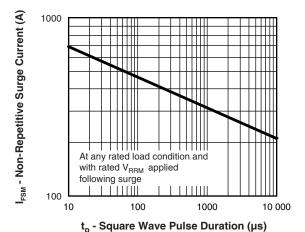


Fig. 7 - Maximum Non-Repetitive Surge Current

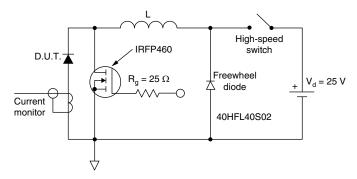


Fig. 8 - Unclamped Inductive Test Circuit

Note

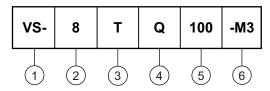
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

VS-8TQ060-M3, VS-8TQ080-M3, VS-8TQ100-M3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (8 = 8 A)

3 - Package:

T = TO-220

Schottky "Q" series

060 = 60 V

5

Voltage ratings

080 = 80 V100 = 100 V

6 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-8TQ060-M3	50	Antistatic plastic tubes						
VS-8TQ080-M3	50	Antistatic plastic tubes						
VS-8TQ100-M3	50	Antistatic plastic tubes						

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?96156						
Part marking information	www.vishay.com/doc?95391						
SPICE model	www.vishay.com/doc?96227						



Vishay Semiconductors

TO-220AC 2L

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIM	MILLIMETERS		HES	NOTES	NOTES S	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355				•	•			

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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